TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP626, TLP626-2, TLP626-4

Programmable Controllers AC / DC-Input Module Telecommunication

The TOSHIBA TLP626, -2 and -4 consist of gallium arsenide infrared emitting diodes connected in inverse parallel, optically coupled to a photo-transistor. The TLP626-2 offers two isolated channels in an eight lead plastic DIP, while the TLP626-4 provides four isolated channels in a sixteen plastic DIP.

- Collector-emitter voltage: 55 V (min)
- Isolation voltage: 5000 Vrms (min)
- UL recognized: UL1577, file no.E67349
- cUL recognized : CSA Component Acceptance Service No. 5A
 - File No.E67349
- Option (D4) type

VDE approved : EN60747-5-5

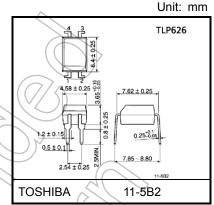
Maximum operating insulation voltage: 890 Vpk Highest permissible over voltage: 8000 Vpk

Note: When an EN 60747-5-5 approved type is needed, please designate the "Option(D4)".

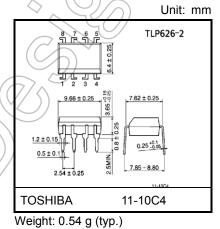
Current transfer ratio

	Curr	\land			
	Cult				
Ole e sifie e tie e		Marking			
Classification		Ta = -25 to 75°C	of		
(Note 1)				Classification	
	$I_F = \pm 1mA$ $V_{CE} = 0.5V$	$I_F = \pm 0.5 mA$	IF = ±1mA VCE = 0.5V		
	$V_{CE} = 0.5V$	V _{CE} = 1.5V	V _{CE} = 0.5V	())	
Rank BV	200%	100%	100%	BV	
Standard	100%	50%	50%	BV, blank	

Note 1: Only TLP626 is applied to BV rank items. Note: Application type name for certification test, please use standard product type name, i.e. TLP626(BV): TLP626



Weight: 0.26 g (typ.)

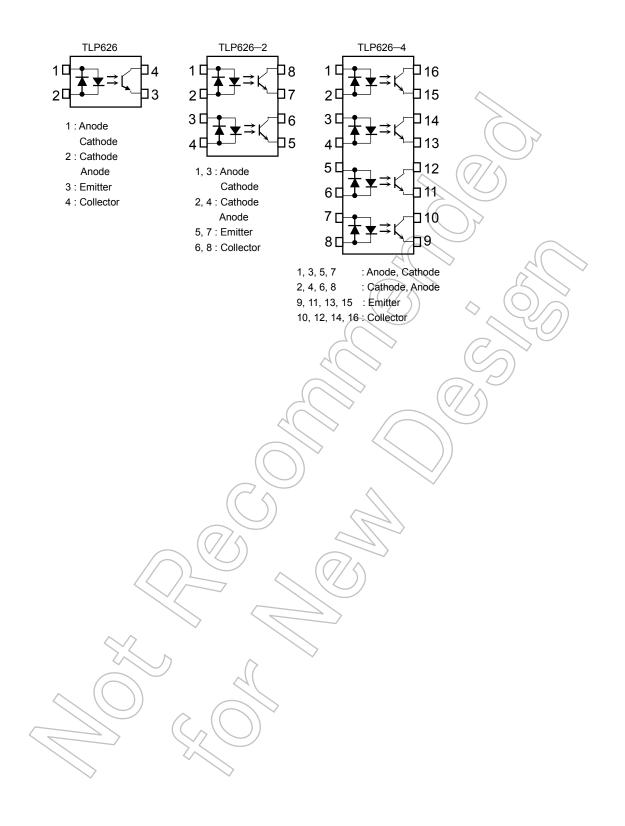


Unit: mm

Weight: 1.1 g (typ.)

Start of commercial production 1984-04

Pin Configuration (top view)



Absolute Maximum Ratings (Ta = 25°C)

			Rat	ing		
	Characteristic	Symbol	TLP626	TLP626-2 TLP626-4	Unit	
	Forward current	IF	60	50	mA	
	Forward current derating	ΔI _F / °C	-0.7 (Ta ≥ 39°C)	-0.5 (Ta ≥ 25°C)	mA / °C	
ED	Pulse forward current		1 (100µs pu	lse,100pps)	А	
Ц	Diode Power dissipation	PD	100	70	mW	
	Diode Power dissipation derating	ΔP _D / °C	-1.2 (Ta ≥ 39°C)	-0.7 (Ta ≥ 25°C)	mW / °C	
	Junction temperature	Tj	412	25	°C	
	Collector-emitter voltage	VCEO	5	5	V	
	Emitter-collector voltage	V _{ECO}	7		V	
ctor	Collector current	IC .	50	0	mA	
Detector	Collector power dissipation (1 circuit)	Pc	150	100	mW	
]	Collector power dissipation derating $(Ta \ge 25^{\circ}C, 1 \text{ circuit})$	ΔPc/°C	-1.5 🛇	1.0	mW / °C	
	Junction temperature	Tj	12	25	°C	
Sto	rage temperature range	Tstg	-55 to	125	°C	
Ope	erating temperature range	Popr	-55 to	100	°C	
Lea	d soldering temperature	T _{sol}	260 (10s)	°C	
Tota	al package power dissipation (1 circuit)	Рт	250	150	mW	
Tota	al package power dissipation derating (Ta $\ge 25^{\circ}$ C, 1 circuit)	ΔP _T /°C	-2.5	-1.5	mW / °C	
Isol	ation voltage (Note 1)	BVS	5000 (AC, 60	s, R.H.≤60%)	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	-	5	24	V
Forward current	IF(RMS)	_	1.6	20	mA
Collector current	lc	_	1	10	mA
Operating temperature	T _{opr}	-25		75	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 1: Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

Electrical Characteristics (Ta = 25°C)

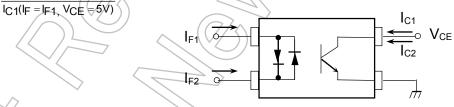
	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	$I_F = \pm 10 mA$	1.0	1.15	1.3	V
LED	Reverse current	lF	VF = ±0.7V	_	2.5	20	μA
	Capacitance	CT	V = 0 V, f = 1MHz	_ <	60		pF
	Collector-emitter breakdown voltage	V(BR)CEO	IC = 0.5mA	55)	1	V
or	Emitter-collector breakdown voltage	V(BR)ECO	IE = 0.1mA	7	L	- ~(V
Detector	Collector dark current	1050	V _{CE} = 24V	for	10	100	nA
ð		ICEO	V _{CE} = 24V, Ta = 85°C	, KA	2	50	μA
	Capacitance collector to emitter	CCE	V=0 V, f=1MHz	X	12	—	pF

Coupled Electrical Characteristics (Ta = 25°C)

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Characteristic	Symbol	Test Condition	Min	Тур	Max	Unit
Current transfer ratio	IC / IF	$I_F = \pm 1$ mA, $V_{CE} = 0.5V$ rank BV(Note 2)	100 200	N T	1200 1200	%
Low input CTR	IC / IF(low)	$I_F = \pm 0.5 \text{mA}$, $V_{CE} = 1.5 \text{V}$ rank BV(Note 2)	50 100	$\widehat{\mathcal{D}}$	7 <u> </u>	%
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 0.5$ mA, $I_F = \pm 1$ mA $I_C = 1$ mA, $I_F = \pm 1$ mA rank BV(Note 2)		- 0.2 -	0.4 — 0.4	V
Off-state collector current	Ic(off)	VF = ±0.7V, VCE = 24V	//-	1	10	μA
CTR symmetry (Note 1)	lc(ratio)	IC(IF = -1mA) / IC(IF = 1mA)	0.5	_	2	_

Note 1

 $IC(ratio) = \frac{I_{C2}(I_F = I_{F2}, V_{CE} = 5V)}{I_{C1}(I_F = I_{F1}, V_{CE} = 5V)}$



Note 2: Only TLP626 is applied to BV rank items.

Coupled Electrical Characteristics (Ta = -25 to 75°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
		IF = 1mA, V _{CE} = 0.5V rank BV(Note 1)	50	_	_	%
Current transfer ratio	IC / IF		100	—	_	70
Low input CTR	I _C / I _F (low)	I _F = 0.5mA, V _{CE} = 1.5V		50		%
		rank BV(Note 1)		100		70

Note 1: Only TLP626 is applied to BV rank items.

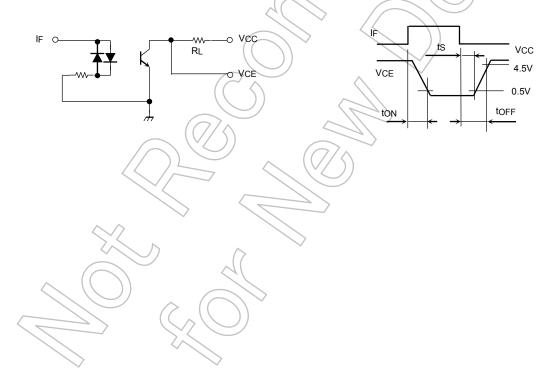
Isolation Characteristics (Ta = 25°C)

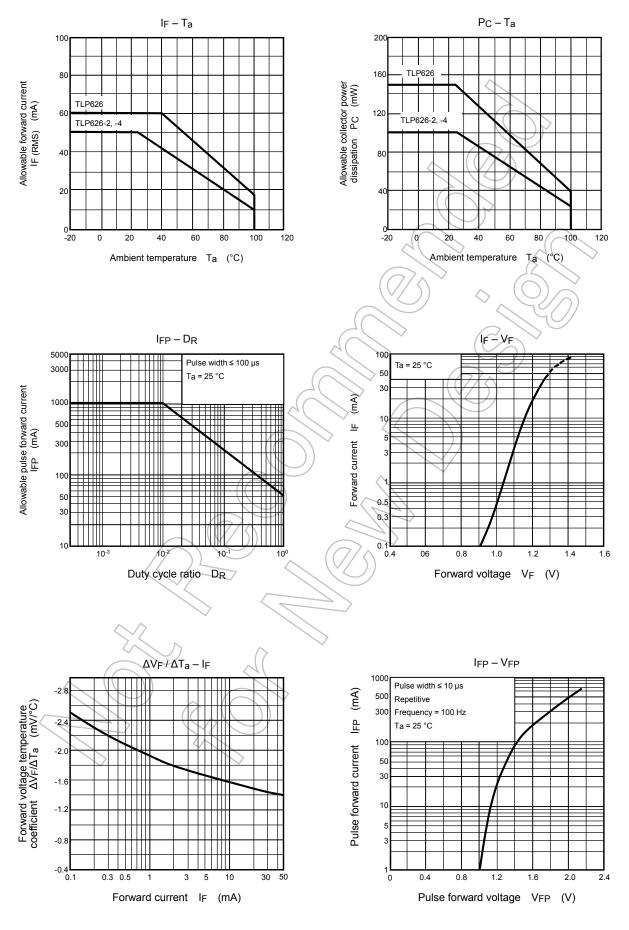
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V, f = 1MHz	_	0.8	-	pF
Isolation resistance	Rs	Vs = 500V, R.H.≤60%	5×10 ¹⁰	10 ¹⁴		Ω
		AC, 60 s	5000 <	/		Vrma
Isolation voltage	BVs	AC, 1 s, in oil	_	10000	1	Vrms
		DC, 60 s, in oil	—	10000	1)^_	Vdc

Switching Characteristics (Ta = 25°C)

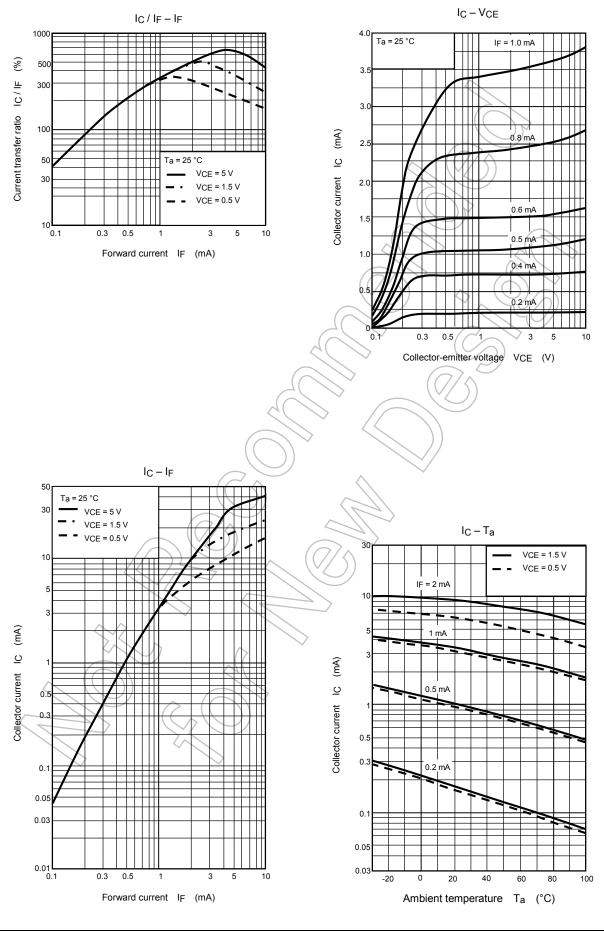
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr	$V_{CC} = 10V, I_C = 2mA$ $R_L = 100\Omega$	1(8	\leq	
Fall time	tf		\sim	8	ZF	
Turn-on time	t _{on}		> _	10	1	µs
Turn-off time	t _{off}		_◇	8	JA)
Turn-on time	ton		-	10	Ś	
Storage time	ts	R _L = 4.7kΩ (Fig.1) V _{CC} = 5 V, I _F = ±1.6mA	-((50	/ _	μs
Turn-off time	tOFF			300	_	

Fig. 1: Switching operating conditions

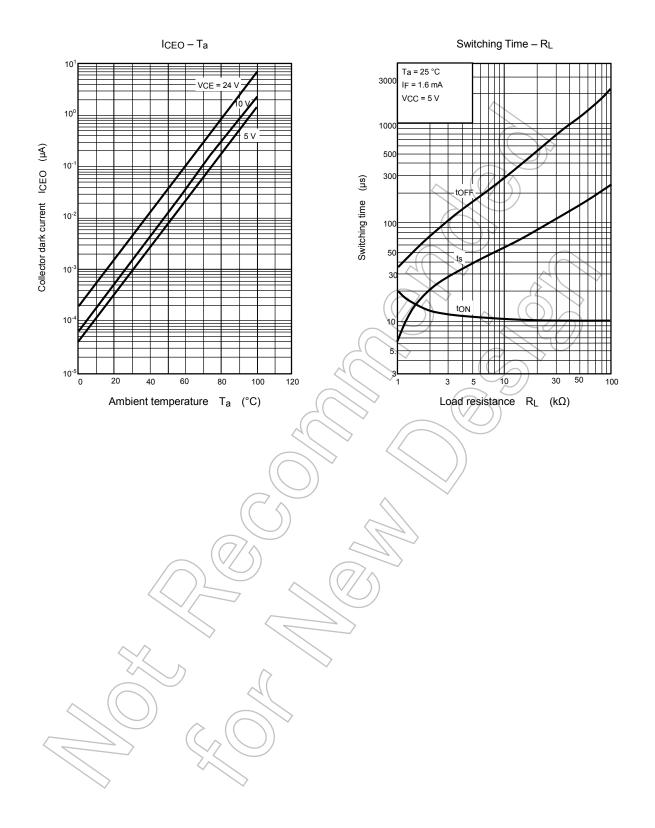




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